

Features

- Low $R_{DS(on)}$ @ $V_{GS}=10V$
- 5V Logic Level Control
- N Channel SOT23-3L Package
- Pb-Free, RoHS Compliant

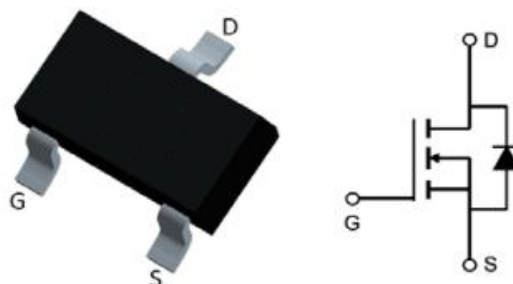
$V_{(BR)DSS}$	$R_{DS(ON)}$ Typ	I_D Max
150V	510m Ω @ 10V	2A
	520m Ω @ 4.5V	

Applications

- LED backlighting
- Industrial power supplies
- Load Switch
- Hand-Held Instruments
- DC/DC Converters

Order Information

Product	Package	Marking	Packing
AM3490N-T1-PF-CN	SOT23-3L	3N15	3000PCS/Reel



SOT23-3L

Absolute Maximum Ratings

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Symbol	Parameter	Rating	Unit	
Common Ratings (T _A =25°C Unless Otherwise Noted)				
V _{GS}	Gate-Source Voltage	±20	V	
V _{(BR)DSS}	Drain-Source Breakdown Voltage	150	V	
T _J	Maximum Junction Temperature	150	°C	
T _{STG}	Storage Temperature Range	-50 to 150	°C	
Mounted on Large Heat Sink				
I _{DM}	Pulse Drain Current Tested①	T _A =25°C	6.8	A
I _D	Continuous Drain Current	T _A =25°C	2.	A
		T _A =70°C	1.6	
P _D	Maximum Power Dissipation	T _A =25°C	1.56	W
		T _A =70°C	1	
R _{θJA}	Thermal Resistance Junction-Ambient	80	°C/W	

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =250μA	150	–	–	V
I _{DSS}	Zero Gate Voltage Drain Current(T _A =25°C)	V _{DS} =150V, V _{GS} =0V	–	–	1	μA
	Zero Gate Voltage Drain Current(T _A =125°C)	V _{DS} =120V, V _{GS} =0V	–	–	100	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	–	–	±100	nA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	2.0	3.0	V
R _{DS(ON)}	Drain-Source On-State Resistance②	V _{GS} =10V, I _D =1A	–	510	620	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance②	V _{GS} =4.5V, I _D =1A	–	520	650	mΩ
Dynamic Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =75V, V _{GS} =0V, f=1MHz	–	308	–	pF
C _{oss}	Output Capacitance		–	10.6	–	pF
C _{rss}	Reverse Transfer Capacitance		–	6	–	pF
R _g	Gate Resistance	f=1MHz		3.5		Ω
Q _g	Total Gate Charge	V _{DS} =75V I _D =1A, V _{GS} =10V	–	3.3	–	nC
Q _{gs}	Gate Source Charge		–	0.7	–	nC
Q _{gd}	Gate Drain Charge		–	0.7	–	nC
Switching Characteristics @ T _J = 25°C (unless otherwise stated)						
t _{d(on)}	Turn on Delay Time	V _{DD} =75V, I _D =1A, R _G =3.3Ω, V _{GS} =10V	–	4.7	–	ns
t _r	Turn on Rise Time		–	1.4	–	ns
t _{d(off)}	Turn Off Delay Time		-	11	–	ns
t _f	Turn Off Fall Time		–	3	–	ns
Source Drain Diode Characteristics @ T _J = 25°C (unless otherwise stated)						
I _{SD}	Source drain current(Body Diode)	T _A =25°C	–	–	1.4	A
V _{SD}	Forward on voltage②	T _J =25°C, I _{SD} =1A, V _{GS} =0V	–	0.78	1.2	V

Notes: ① Pulse width limited by maximum allowable junction temperature

②Pulse test ; Pulse width≤300μs, duty cycle≤2%.

Typical Characteristics

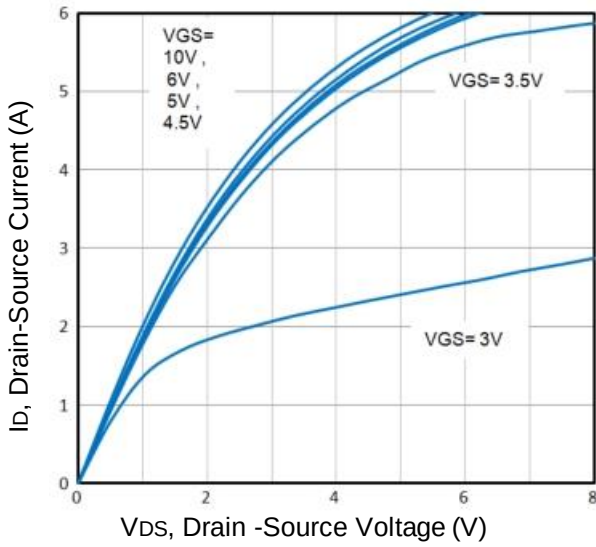


Fig1. Typical Output Characteristics

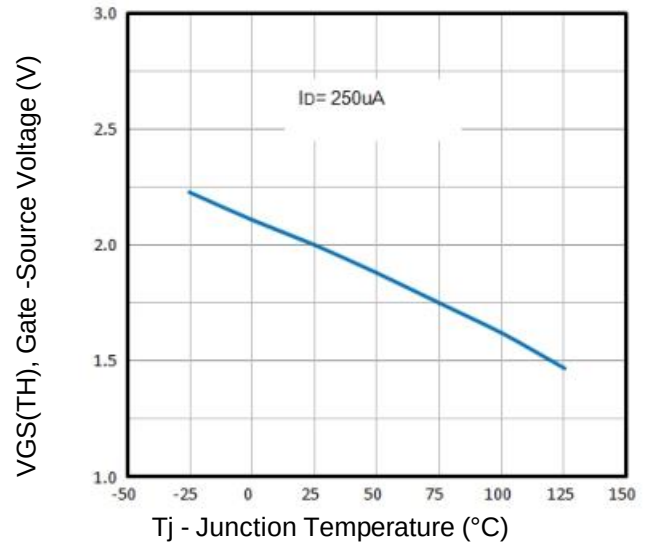


Fig2. VGS(TH) Voltage Vs. Temperature

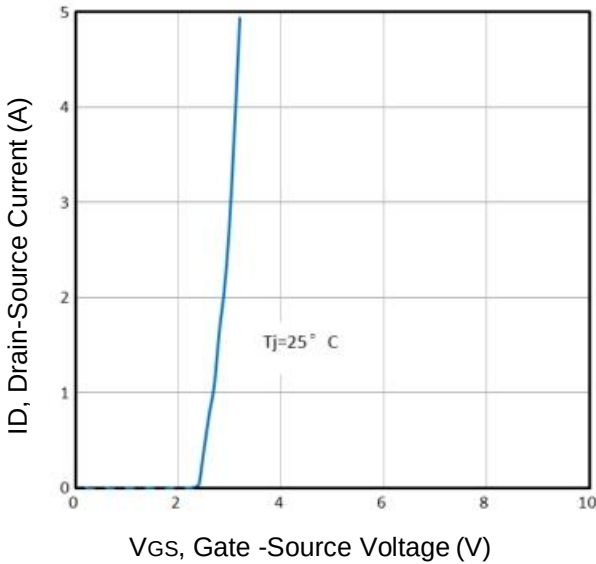


Fig3. Typical Transfer Characteristics

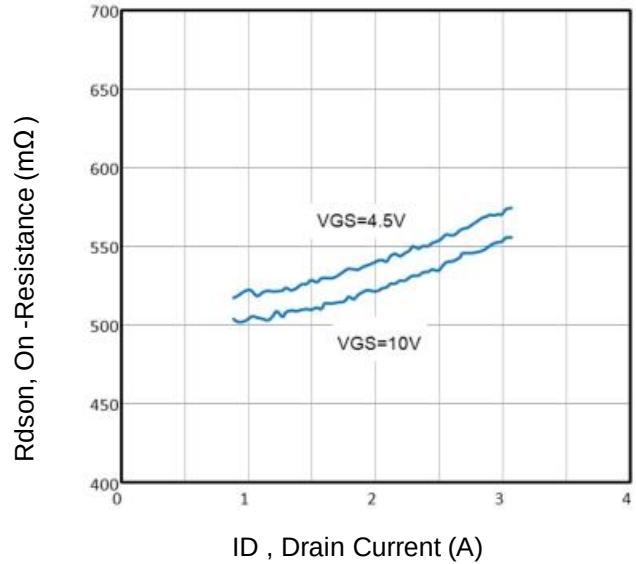


Fig4. On-Resistance vs. Drain Current and Gate

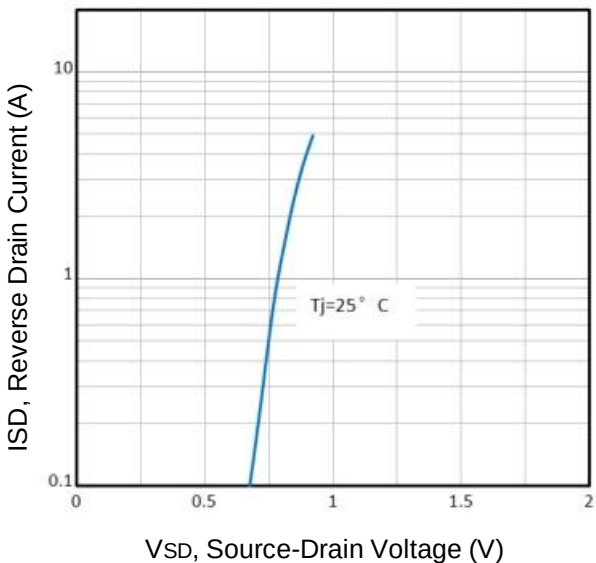


Fig5. Typical Source-Drain Diode Forward Voltage

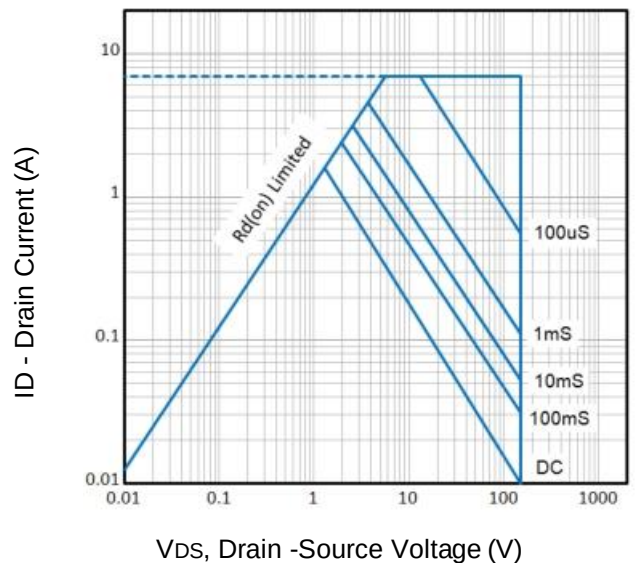


Fig6. Maximum Safe Operating Area

Typical Characteristics

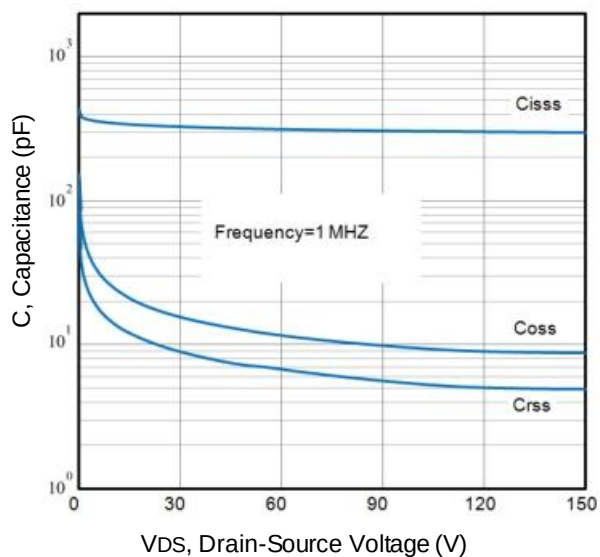


Fig7. Typical Capacitance Vs. Drain-Source Voltage

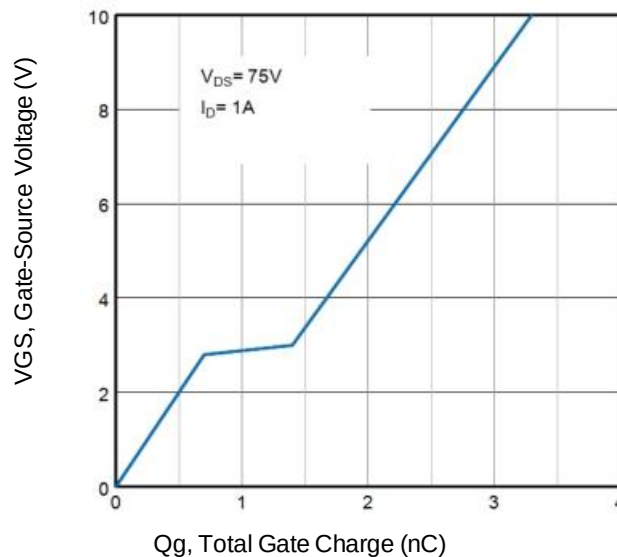


Fig8. Typical Gate Charge Vs. Gate-Source Voltage

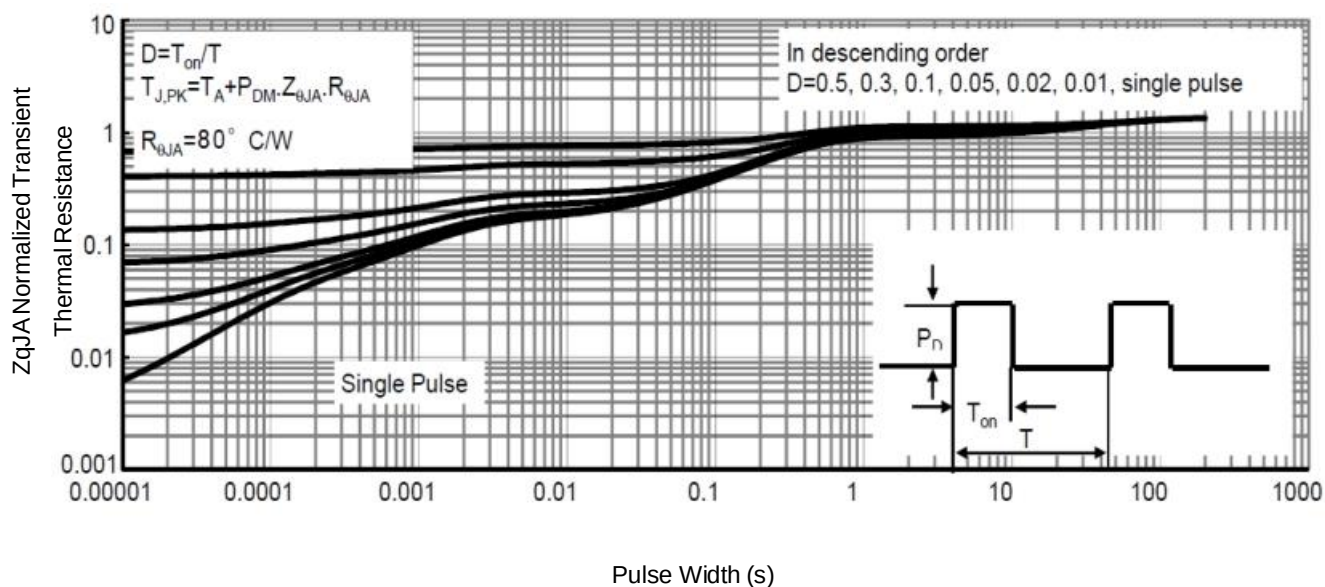


Fig9. Normalized Maximum Transient Thermal Impedance

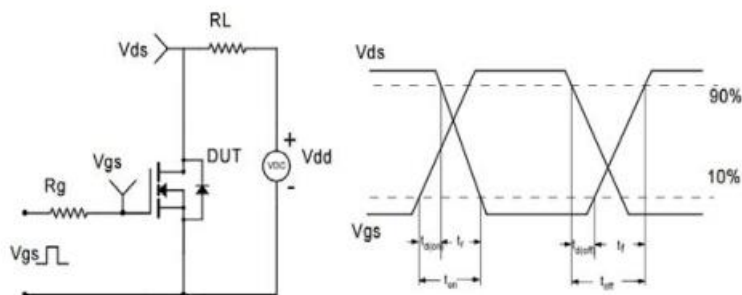
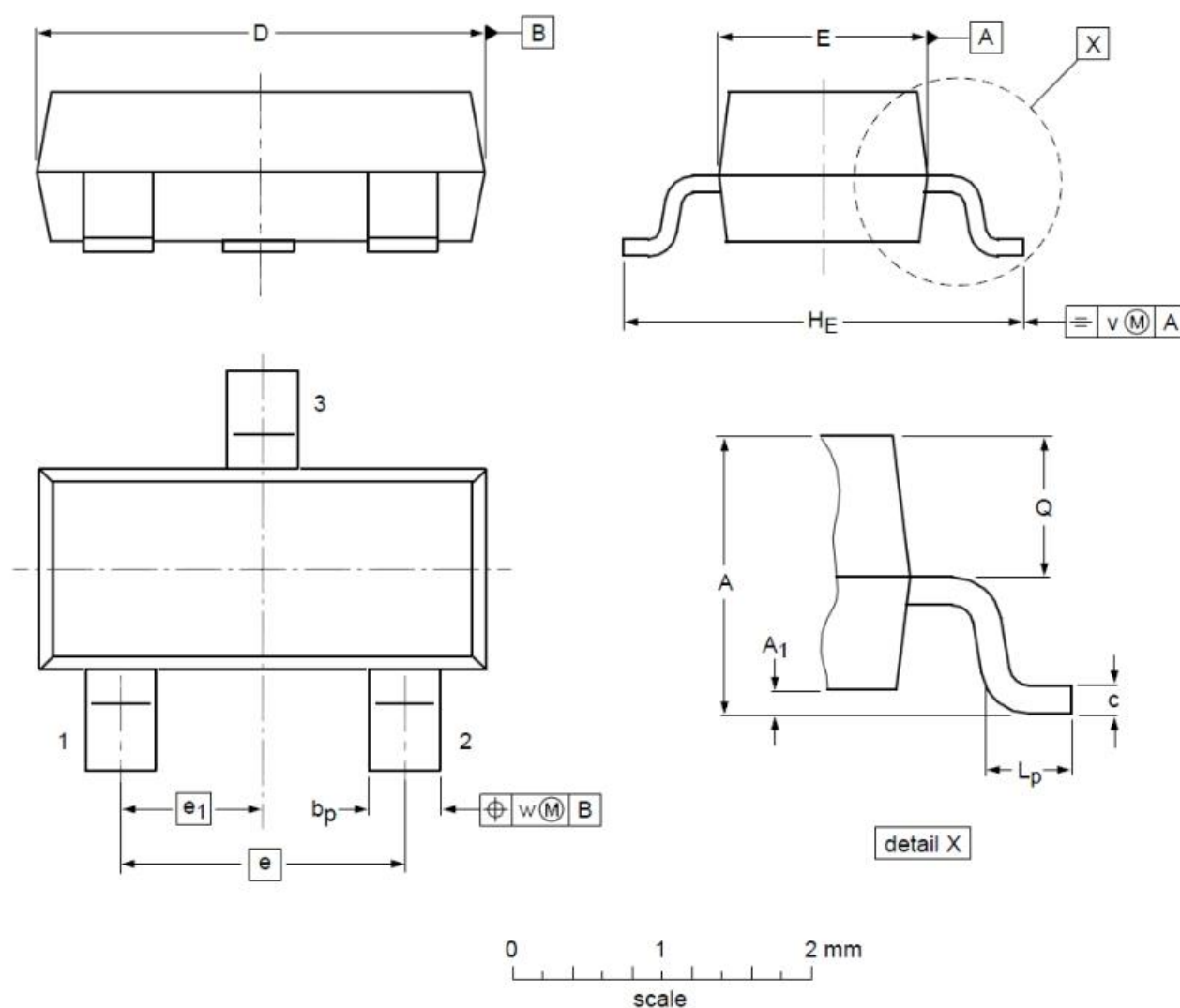


Fig10. Switching Time Test Circuit and waveforms

SOT23-3L Mechanical Data

DIMENSIONS (unit : mm)

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	1.00	1.17	1.30	A ₁	0.01	0.05	0.10
b _p	0.35	0.39	0.50	c	0.10	0.20	0.26
D	2.70	2.90	3.10	E	1.50	1.60	1.70
e	--	1.90	--	e ₁	--	0.95	--
H _E	2.50	2.78	3.00	L _p	0.20	0.32	0.60
Q	0.23	0.27	0.33	v	--	0.20	--
w	--	0.20	--				

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